

ECE590-03
Enterprise Storage Architecture

Fall 2016

Survey of Next-Generation Storage

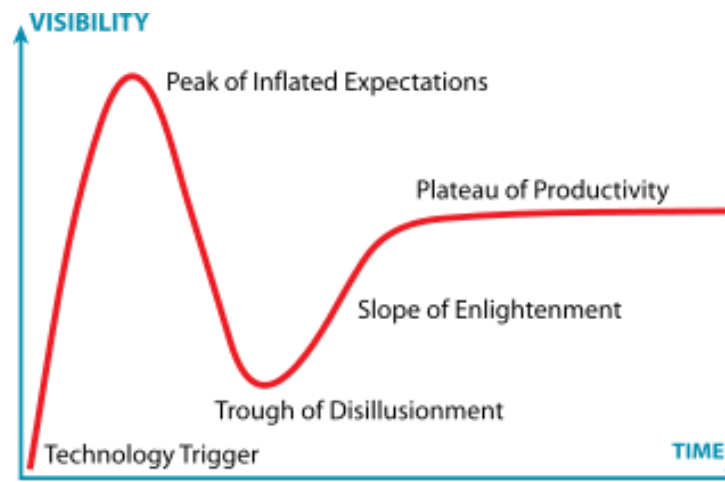
Tyler Bletsch
Duke University

Lots of possible avenues...

- Wikipedia “list of emerging technologies” for storage:

Emerging technology ⇅	Status ⇅	Potentially marginalized technologies ⇅	Related articles ⇅
Emerging memory technologies	In development	Current memory technologies	T-RAM, memristor, Z-RAM, TTRAM, CBRAM, SONOS, RRAM, Racetrack memory, NRAM, Phase-change memory, FJG RAM, Millipede memory, Skyrmion, Programmable metallization cell, 3D XPoint, Ferroelectric RAM, Magnetoresistive random-access memory, nvSRAM
Emerging magnetic data storage technologies	In development (HAMR, BPM); diffusion (SMR)		SMR, HAMR, BPM, MAMR, TDMR, CPP/GMR, PMR, Hard disk drive

- That’s a lot of things! Most won’t pan out
- Temper your excitement, remember the hype cycle...



Areas of focus

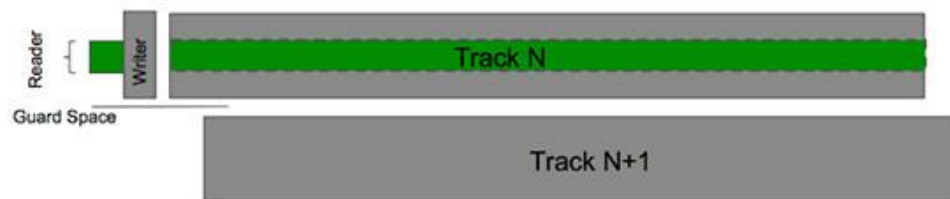
- Improving HDDs
 - Shingled magnetic recording (SMR)
 - Heat-assisted magnetic recording (HAMR)
 - Bit-patterned media (BPM)
 - Just pump a bunch of helium into there
- Improving SSDs
 - 3D NAND structures
- New solid-state memories
 - Phase-change memory (PCM)
 - Ferroelectric RAM (FRAM)
 - Magnetoresistive RAM (MRAM)
 - Resistive RAM (RRAM)
 - Conductive Bridging RAM (CBRAM)
- Memristors: are they a thing?
- Theoretical and proof-of-concept stuff

Improving HDDs

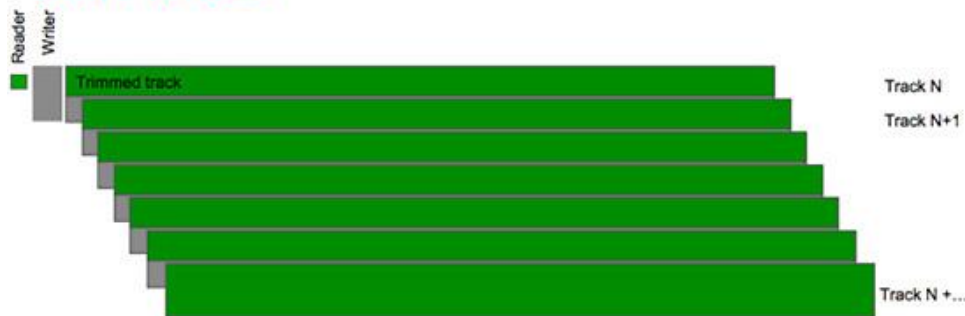
Shingled magnetic recording (SMR)

- Due to physics reasons, the write head is always bigger than the read head
 - This means that we write a track of X width, but we just read the middle $X/2$ of it back.
 - Tracks aren't allowed to overlap, so this leads to waste
- Solution: let them overlap, and deal with resulting destruction

Conventional Writes



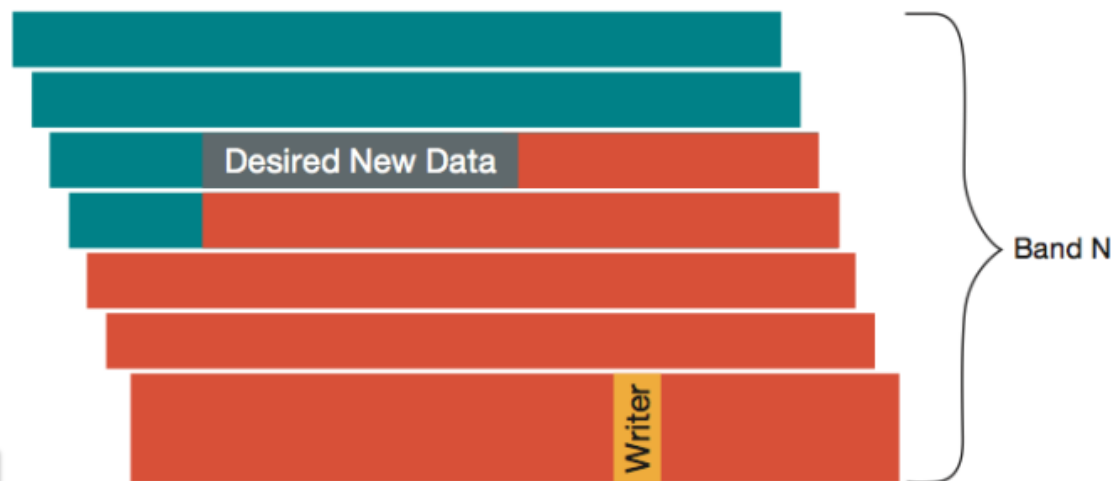
SMR Writes



Feasible? **Yes**. Seagate started shipping in 2013.

Shingled magnetic recording (SMR)

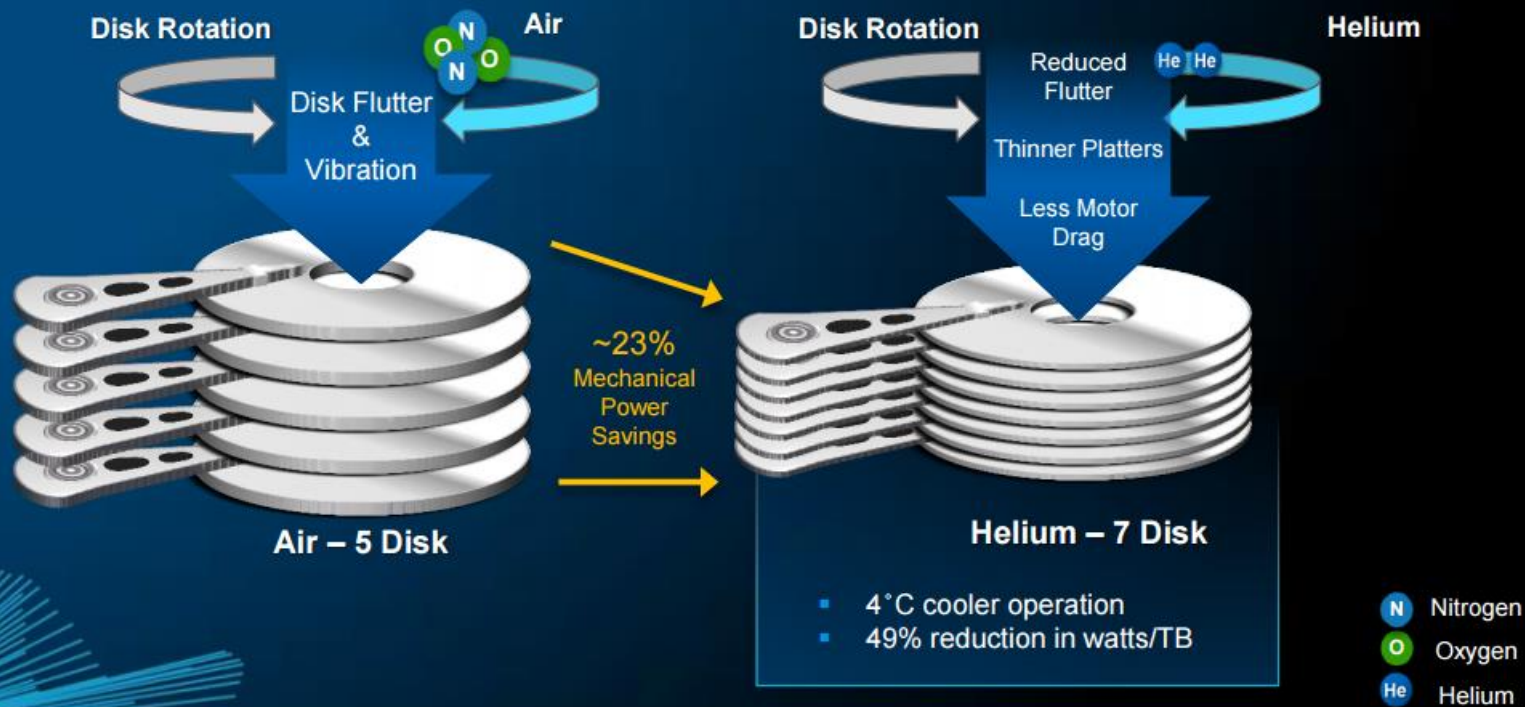
- Dealing with overlap
 - Drive reads neighboring data under threat from a pending write; restores it afterward.
 - If we blindly do that to whole drive, then single write means rewriting whole drive...
 - Solution: Do SMR on track groups.
 - Wow! HDD now like SSD: Small read sectors, big erasure blocks!
 - Lots of cache and optimization opportunities...



Feasible? **Yes**. Seagate started shipping in 2013.

Seal the HDD and fill with helium

- Reduces mechanical power dissipated in air shear
- Allows platters to be placed closer together enabling more capacity

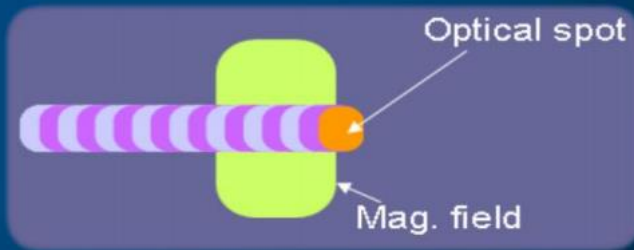


From “[Navigating Storage in a Cloudy Environment](#)” by Steve Campbell, HGST.

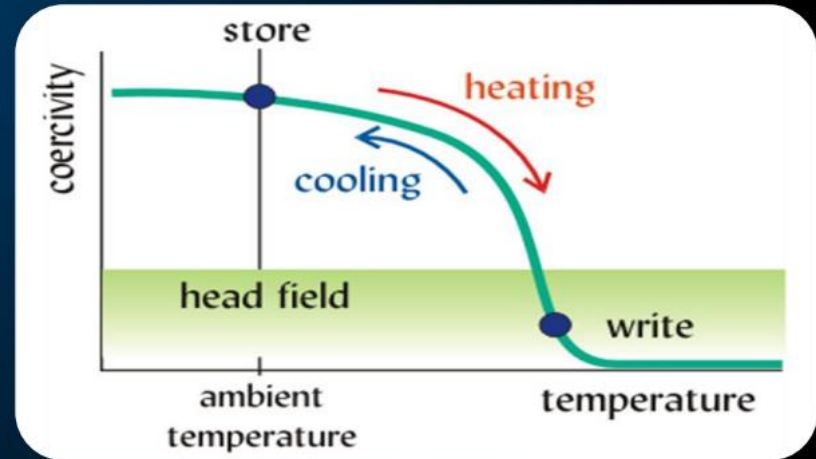
Heat-Assisted Magnetic Recording (HAMR)

HAMR : A Whole New Recording System

- Density growth limited by ability to make smaller bits thermally stable
- HAMR combines laser and magnetic field to write the media
- Allows for use of much higher coercivity media and hence enables higher densities



$$\frac{dH_{eff}}{dx} = \frac{dH_k}{dT} \cdot \frac{dT}{dx}$$

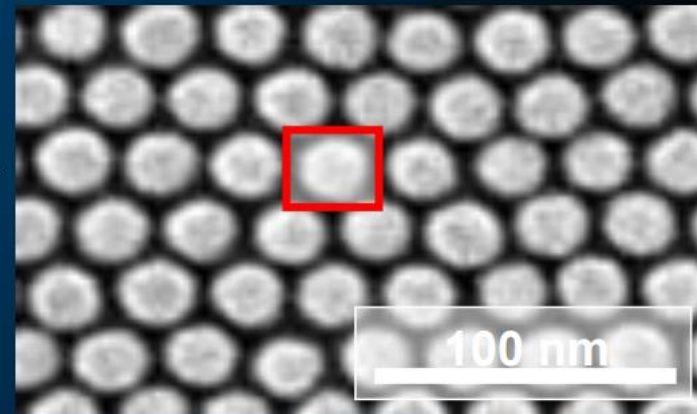
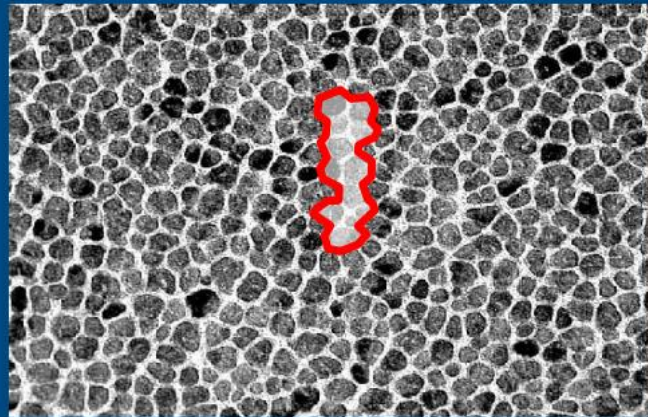


Industry projecting the introduction of HAMR technology in 2016-2017

Bit Patterned Media

Granular Media

versus Bit Patterned Media



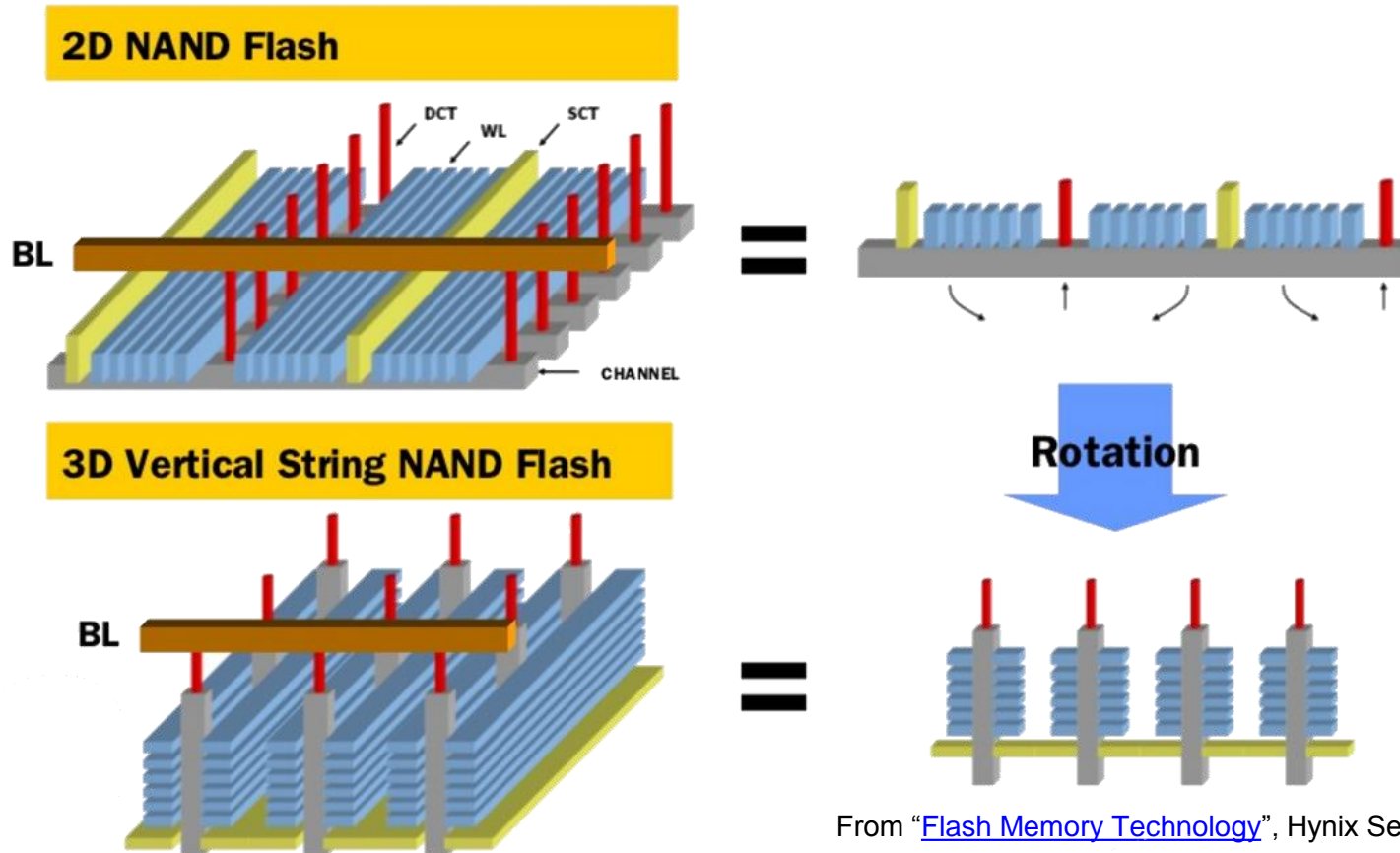
- Extend density by replacing randomly sputtered grains with very uniform, lithographically-defined magnetic islands
- The challenge for bit patterned media is how to fabricate these very small islands precisely and cost-effectively
- Feature sizes will need to be smaller than semiconductor

Have already demonstrated all the steps necessary for 13nm half pitch

Improving SSDs

3D NAND structures

- Current SSD/flash design: NAND gates laid out in 2D

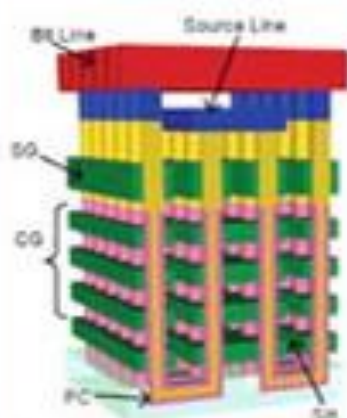
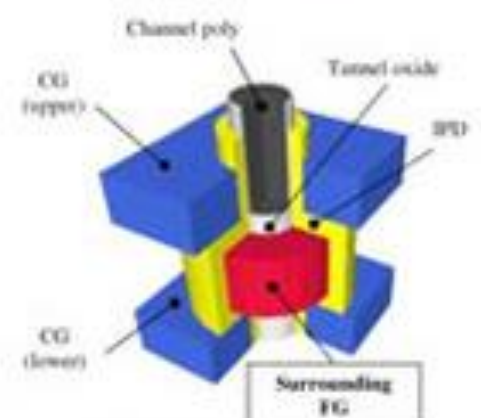
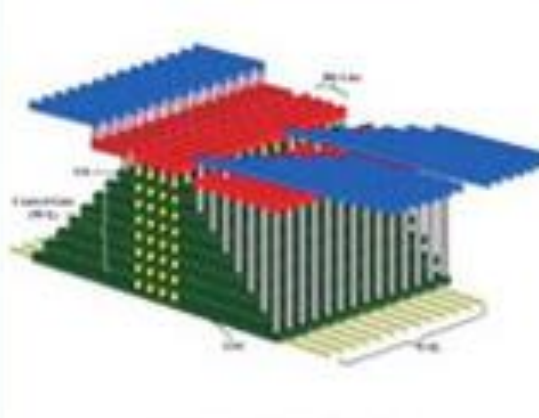


From "[Flash Memory Technology](#)", Hynix Semiconductor.

- Novel idea: Make it 3D. Lots of ways to do this...

3D NAND structures

- Lots of ways to do this...

	Toshiba/P-BICS	Hynix DC-SF	Samsung/TCAT
Type of 3D NAND	 <p>R. Katsumata et al, VLSI 2009</p>	 <p>S Whang et al, IEDM 2010</p>	 <p>J. Jang et al, VLSI 2009</p>
Transistor	Gate all around; Salicided Poly Si gate	Gate all around; Salicided Poly Si gate	Gate all around; Damascene metal gate
Storage	Charge trap	Floating gate	Charge trap

From "3D NAND Approaches", IMW 2011. [Figure from here.](#)

New solid state memories

Phase-change memory (PCM)

- Fundamental enabler: Chalcogenide glass
 - A glass compound with sulfur, selenium, or other additive
 - Rate of heating/cooling can produce **amorphous** or **crystalline** structure
 - Two structures behave very differently optically and electrically
- This is what makes re-writable CD/DVDs possible
- To “write”:
 - Melt with brief, hot pulse of heat; rapid cooling gives amorphous state
 - Melt with long, low-intensity heat; slow cooling gives crystalline state
- To “read”:
 - Crystalline is low resistance, amorphous is high resistance
 - Measure resistance with circuit, decide which one means “1”



Crystalline

Low Ω

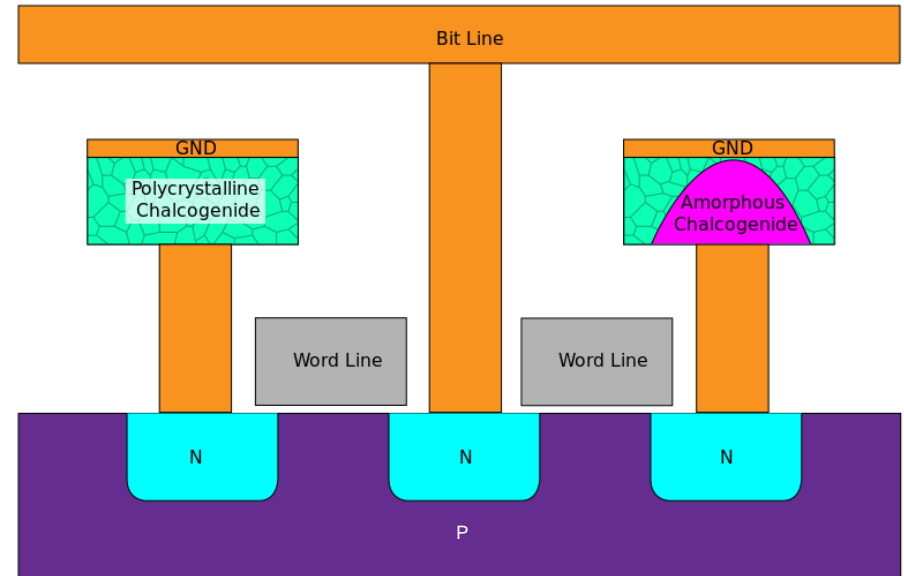


Amorphous

High Ω

Phase-change memory (PCM)

- Array these elements in a grid like any other RAM
- Use electricity to heat cells (write) and to determine their resistance (read)



“A cross-section of two PRAM memory cells. One cell is in low resistance crystalline state, the other in high resistance amorphous state.”

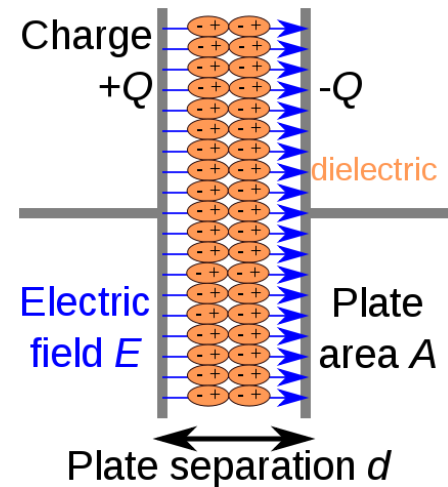
From Wikipedia, “[Phase-change memory](#)”

Feasible? **Technically, yes; economically, maybe.**

- Shipping memory chips available from many vendors
- Large-scale adoption hasn't happened; flash still wins for most use cases when you factor in cost
- Roller-coaster development history:
 - In 2012, Micron announced PCM for mobile devices ([src](#))
 - In 2014, flash had gotten better (e.g. 3D NAND), and Micron ditched PCM! ([src](#))
 - In 2015, PCM appeared dead, but then Western Digital showed a PCM prototype with 3 million IOPS ([src](#))
 - Intel/Micron's “3D Xpoint memory” is a PCM released in 2016 ([src](#))

Ferroelectric RAM (FRAM)

- Like DRAM, but uses a “**ferroelectric**” layer instead of the DRAM capacitors’ dielectric.
- Ferroelectric material: Material that has an electric polarization which can be flipped
 - Material consists of polarized molecules (one side positive, other side negative)
 - If you flip one molecule, attraction/repulsion resets it
 - Stable, self-correcting
 - Apply enough voltage, flip *all* molecules
 - Settable!



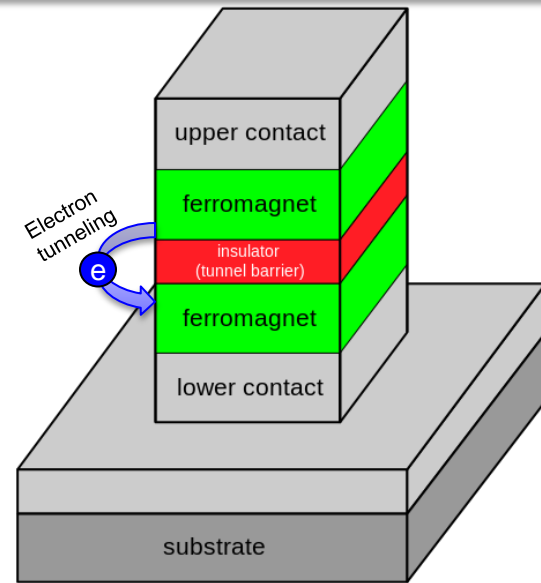
From Wikipedia, "[Ferroelectric capacitor](#)"

Feasible? **Technically, yes; economically, maybe.**

- Shipping memory chips available from vendors
- Large-scale adoption hasn't happened; seems unlikely under current trends
- Density isn't great (130nm), but lower power than flash
- Current niche: storage for very-low-power embedded systems

Magnetoresistive RAM (MRAM)

- Uses a “**ferromagnetic**” material
 - Metal that can change magnetic field to match an external field (e.g., normal iron)
- Exploits “**tunnel magnetoresistance**”
 - Due to wacky probabilistic quantum physics, an electron in the top layer can “tunnel” (randomly transposition to) the bottom layer
 - If both magnets have same polarity, this tunneling is much more likely ([src](#))
 - Macroscopic effect: resistance is lower
- Can flip magnetic polarity with electrically-created field (write), determine polarity by measuring resistance (read)



From Wikipedia, “[Tunnel magnetoresistance](#)”

Feasible? **Technically, yes; economically, maybe.**

- Only one shipping commercial part (a 4Mbit chip from Everspin)
- Large-scale adoption hasn't happened; seems uncertain
- Density is lousy (180nm), but great performance and lower power than FRAM
- Current niche: storage for very-low-power embedded systems
- Various rumors and promises of upcoming chips from larger vendors (...?)

Others

- Conductive bridging RAM (CBRAM): Electrochemical reaction changes resistivity of cells.
 - Development startup Adesto holds the intellectual property, limited products have been realized.

Feasible? Technically, yes; economically, unlikely?

- Resistive RAM (RRAM): Create/fill electron “vacancies” in a thin oxide layer; changes resistivity of cells.
 - Various small commercial chips exist in the kB range.

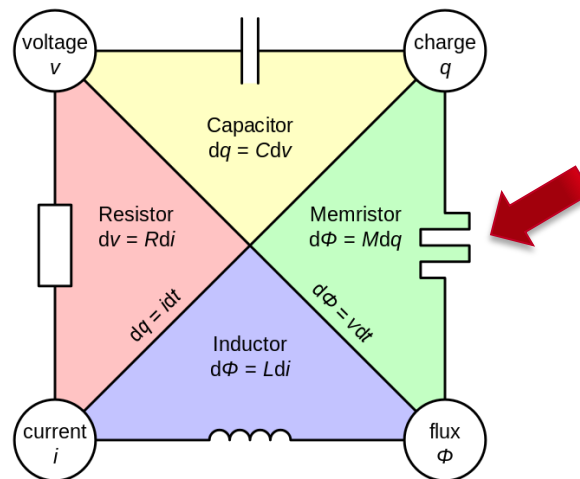
Feasible? Technically, yes; economically, unlikely?

- “Millipede memory”: Create and fill microscopic holes in a thin polymer.
 - In 2005, IBM was aiming to have this out within 2 years, but other forms of storage advanced faster and wrecked it

Feasible? Technically, ???; economically, dead.

Memristors: are they a thing?

- Memristor: A theoretical circuit element that changes resistance based on past current
 - Existence was proposed by taxonomy in 1971:
“If we have components that relate charge, voltage, current, and magnetic flux, shouldn't this thingy exist”? ([src](#))

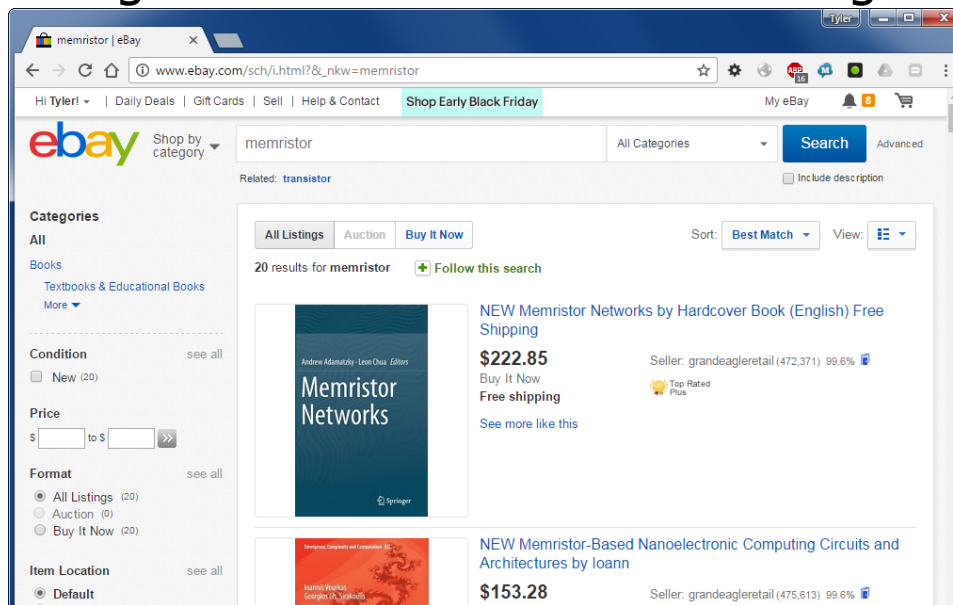


From Wikipedia, "[Memristor](#)"

- By 2011 we didn't a good one, but we liked the name, so it changed to:
“Any 2-terminal thing that changes resistance” ([src](#))

Memristors: are they a thing?

- Problem: We just changed the definition so that it matches most of the proposed non-volatile RAMs we've discussed!
- Result: LOTS OF CONFUSION.
 - Technology press: **"Memristors are the next big thing!"**
 - Actual semiconductor engineers working on this: "wtf are you talking about?"
- My opinion: "memristor" isn't a useful concept. Either:
 - It doesn't exist (original definition), or
 - It is achieved through a dozen different unrelated physical processes (new definition).
- The following shows that it's not a real thing:



**Nothing but a few journals;
no actual components to buy!**

Speculative future stuff

AKA "A list of things that almost never pan out,
except when they do"

Theoretical and proof-of-concept stuff

- Spintronics: Trying to do stuff with the quantum “spin” of electrons
- “Nano-RAM”: Storing data based on position of carbon nanotubes on a chip substrate
- Skyrmion: A hypothetical quantum particle related to magnetism
 - This is a literal sentence used to describe these:
“A two-dimensional magnetic skyrmion, as a topological object, is formed, e.g., from a 3D effective-spin “hedgehog” (in the field of micromagnetics: out of a so-called “Bloch point” singularity of homotopy degree +1) by a stereographic projection, whereby the positive north-pole spin is mapped onto a far-off edge circle of a 2D-disk, while the negative south-pole spin is mapped onto the center of the disk.”
 - If that makes sense to you, invest in Skyrmion companies I guess?

Any of these feasible?
WHO KNOWS??

Theoretical and proof-of-concept stuff

- DNA: Yeah, we'll just encode data in DNA!
 - Ignore the fact that existing life doesn't do arbitrary writes operations on DNA (cells copy, viruses splice, meiosis mixes, and epigenetics alters attached methyl groups, but **nothing** makes arbitrary in-place changes)
 - Ignore that every aspect of DNA's evolution has been focused on protein synthesis, not specific "reads" of DNA locations
 - Ignore that even the fastest and most common IO pattern for DNA, copying during mitosis, takes on the order of hours, giving a data rate of around 60 kBps (similar to a dial-up modem)
 - No, DNA is the definitely the perfect way to store my pirated movies

